



SSCE12V22N1

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Low-Capacitance Bidirectional Micro Packaged TVS Diodes for ESD Protection

● Description

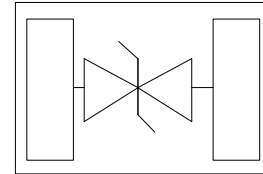
The SSCE12V22N1 is designed with AF Punch-Through process TVS technology to protect voltage sensitive components from ESD. Excellent clamping capability, low leakage, and fast response time provide best in class protection on designs that are exposed to ESD. Because of its small size, it is suited for use in cellular phones, MP3 players, digital cameras and many other portable applications where board space comes at a premium. Also because of its low capacitance, it is suited for use in high frequency designs such as USB 2.0 high speed, VGA, DVI, SDI and other high speed line applications.

It has been specifically designed to protect sensitive components which are connected to high-speed data and transmission lines from overvoltage caused by ESD(electrostatic discharge), CDE (Cable Discharge Events),and EFT (electrical fast transients).

● Feature

- ✧ 100W peak pulse power (TP = 8/20μs)
- ✧ DFN1006-2L Package
- ✧ Working voltage: 12V
- ✧ Low clamping voltage
- ✧ Low capacitance
- ✧ RoHS compliant transient protection for high speed data lines to IEC61000-4-2(ESD)±25kV(air),±25kV(contact)

● PIN configuration



Top view

● Applications

- ✧ DVI & HDMI Port Protection
- ✧ Serial and Parallel Ports
- ✧ Projection TV
- ✧ Notebooks, Desktops, Server
- ✧ USB 1.1/2.0/3.0/3.1/OTG

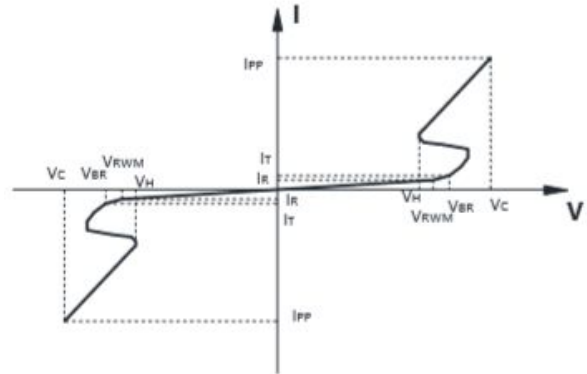
● Mechanical data

- ✧ Lead finish:100% matte Sn(Tin)
- ✧ Mounting position: Any
- ✧ Qualified max reflow temperature:260°C
- ✧ Device meets MSL 1 requirements
- ✧ Pure tin plating: 7 ~ 17 um



● **Electronic Parameter**

Symbol	Parameter
V_{RWM}	Peak Reverse Working Voltage
I_R	Reverse Leakage Current @ V_{RWM}
V_{BR}	Breakdown Voltage @ I_T
I_T	Test Current
I_{PP}	Maximum Reverse Peak Pulse Current
V_C	Clamping Voltage @ I_{PP}
P_{PP}	Peak Pulse Power
C	Junction Capacitance



● **Absolute maximum rating @TA=25°C**

Symbol	Parameter	Value	Units
P_{PP}	Peak Pulse Power (8/20 μ S)	100	W
T_{STG}	Storage Temperature	-55/+150	°C
T_J	Operating Temperature	-55/+150	°C

● **Electrical Characteristics @TA=25°C**

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
Peak Reverse Working Voltage	V_{RWM}	Any I/O to Ground		12		V
Breakdown Voltage	V_{BR}	$I_T = 1\text{mA}$ Any I/O to Ground	13.3	14.3		V
Reverse Leakage Current	I_R	$V_{RWM} = 12\text{V}$, $T = 25^\circ\text{C}$		0.01	0.2	μA
Clamping Voltage	V_C	$I_{PP} = 1\text{A}$, $t_P = 8/20\mu\text{s}$		13.9		V
Clamping Voltage	V_C	$I_{PP} = 5\text{A}$, $t_P = 8/20\mu\text{s}$		16	20	V
Junction Capacitance	C_J	$V_R = 0\text{V}$, $f = 1\text{MHz}$, any I/O pin to Ground		3.5	5	pF



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● Typical Performance Characteristics

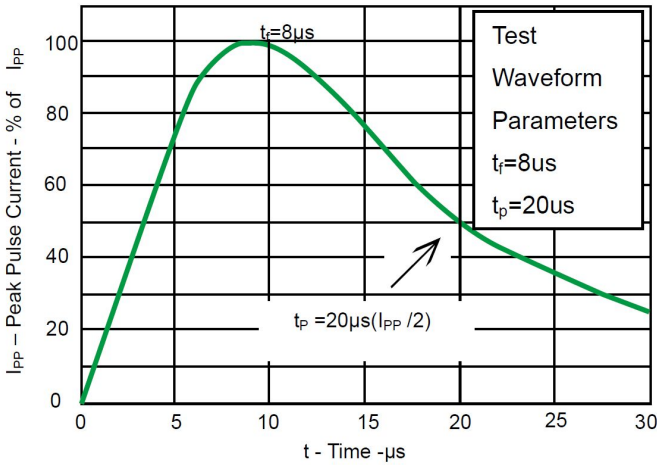


Fig 1. Pulse Waveform

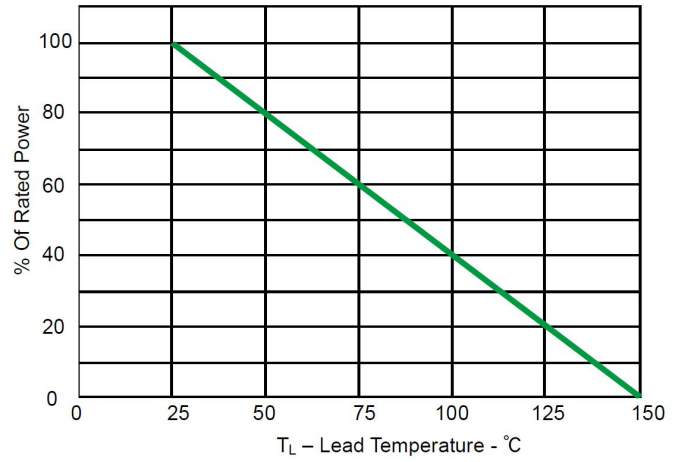
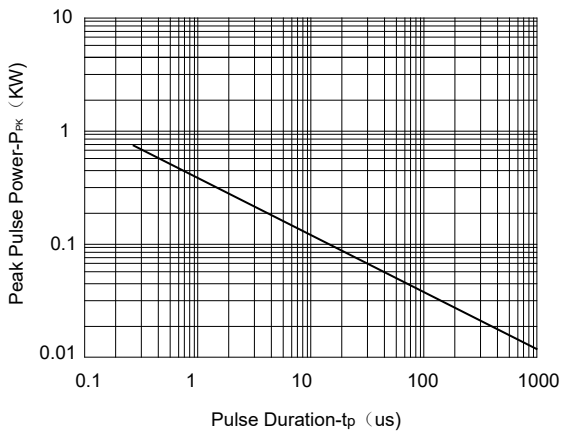


Fig 2. Power Derating Curve



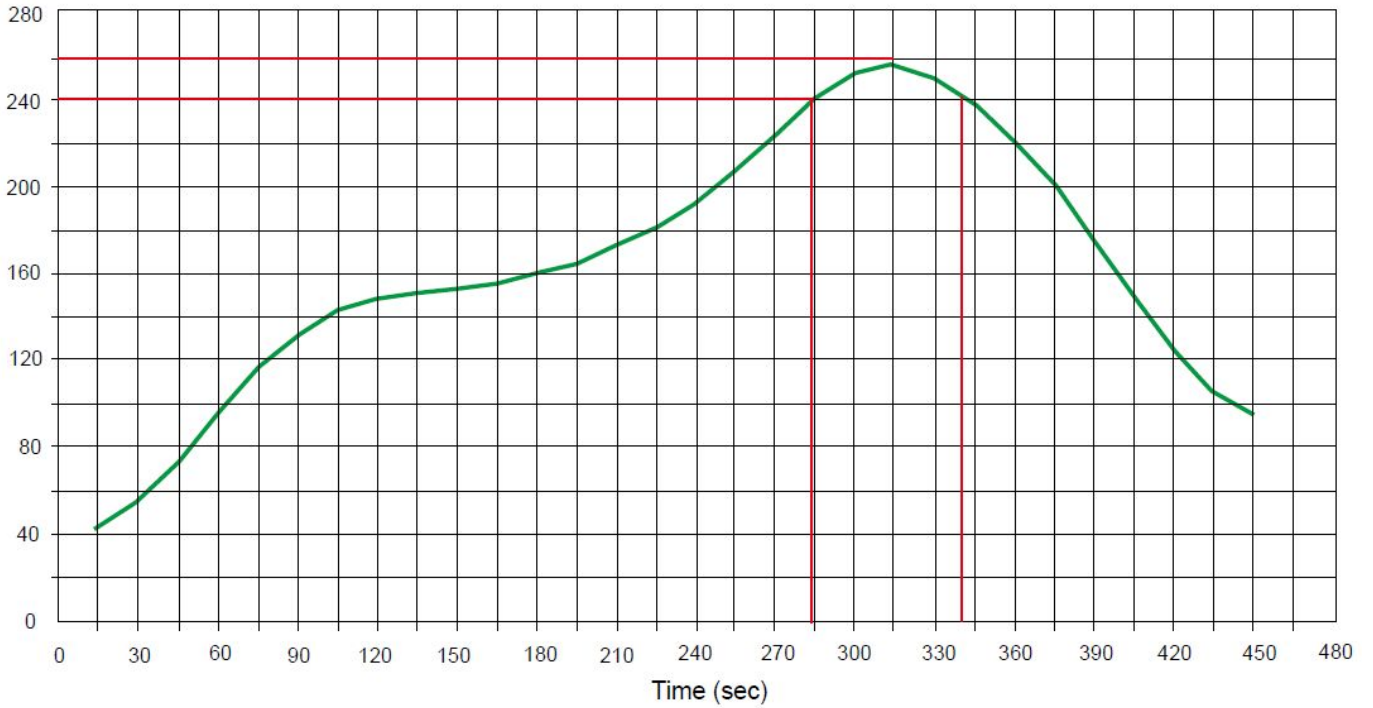
Non-Repetitive Peak Pulse Power vs. Pulse Time



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- Solder Reflow Recommendation

Peak Temp=257°C, Ramp Rate=0.802deg. °C/sec





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- **Package Information**

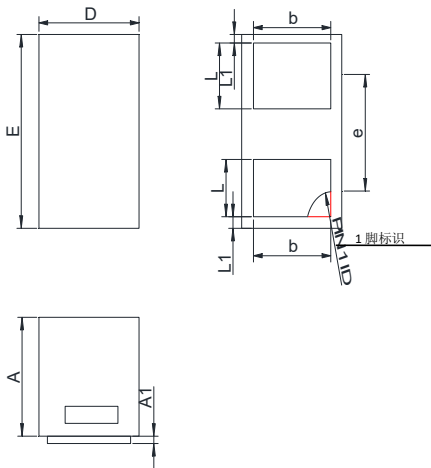
Ordering Information

Device	Package	Qty per Reel	Reel Size
SSCE12V22N1	DFN1006-2L	10000	7 Inch

Mechanical Data

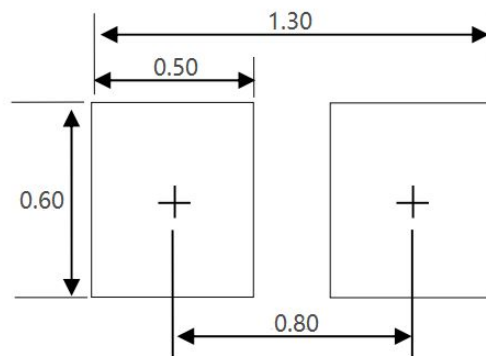
Case:DFN1006-2L

Case Material: Molded Plastic. UL Flammability



DIM	Millimeters	
	Min	Max
A	0.45	0.55
A1	0.00	0.05
D	0.55	0.65
E	0.95	1.05
b	0.45	0.60
e	0.65TYP	
L	0.2	0.3
L1	0.05REF	

Recommended Pad outline



Unit:mm



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